

CDM7-700LR

**SURFACE MOUNT SILICON
N-CHANNEL
LR POWER MOSFET
7.0 AMP, 700 VOLT**



www.centrasemi.com

ULTRAMOS™



DPAK CASE

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CDM7-700LR is a 700 Volt N-Channel MOSFET designed for high voltage, fast switching applications such as Power Factor Correction (PFC), lighting and power inverters. This UltraMOS™ MOSFET combines high voltage capability with low $r_{DS(ON)}$, low threshold voltage, and low gate charge for optimal efficiency.

MARKING: FULL PART NUMBER

APPLICATIONS:

- Solid State Lighting (SSL)
- Alternative energy inverters
- Power Factor Correction

FEATURES:

- High voltage capability ($V_{DS}=700V$)
- Low gate charge ($Q_{gs}=2.5nC$)
- Low $r_{DS(ON)}$ (0.48Ω)

MAXIMUM RATINGS: ($T_C=25^\circ C$ unless otherwise noted)

	SYMBOL		UNITS
Drain-Source Voltage	V_{DS}	700	V
Gate-Source Voltage	V_{GS}	30	V
Continuous Drain Current (Steady State)	I_D	7.0	A
Maximum Pulsed Drain Current, $t_p=10\mu s$	I_{DM}	25	A
Continuous Source Current (Body Diode)	I_S	7.0	A
Maximum Pulsed Source Current (Body Diode)	I_{SM}	25	A
Single Pulse Avalanche Energy (Note 1)	E_{AS}	260	mJ
Power Dissipation	P_D	36	W
Operating and Storage Junction Temperature	T_J, T_{stg}	-55 to +150	$^\circ C$
Thermal Resistance	θ_{JC}	3.47	$^\circ C/W$
Thermal Resistance	θ_{JA}	62	$^\circ C/W$

Note1: $L=79mH, I_{AS}=2.5A, V_{DD}=100V, R_G=25\Omega$, Initial $T_J=25^\circ C$

ELECTRICAL CHARACTERISTICS: ($T_C=25^\circ C$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_{GSSF}, I_{GSSR}	$V_{GS}=30V, V_{DS}=0$		10	100	nA
I_{DSS}	$V_{DS}=700V, V_{GS}=0$		0.040	1.0	μA
BV_{DSS}	$V_{GS}=0, I_D=250\mu A$	700			V
$V_{GS(th)}$	$V_{GS}=V_{DS}, I_D=250\mu A$	2.0	3.3	4.0	V
V_{SD}	$V_{GS}=0, I_S=7.0A$		0.87	1.4	V
$r_{DS(ON)}$	$V_{GS}=10V, I_D=3.5A$		0.48	0.60	Ω
C_{rss}	$V_{DS}=100V, V_{GS}=0, f=1.0MHz$		2.45		pF
C_{iss}	$V_{DS}=100V, V_{GS}=0, f=1.0MHz$		561		pF
C_{oss}	$V_{DS}=100V, V_{GS}=0, f=1.0MHz$		26.9		pF

R1 (17-September 2015)

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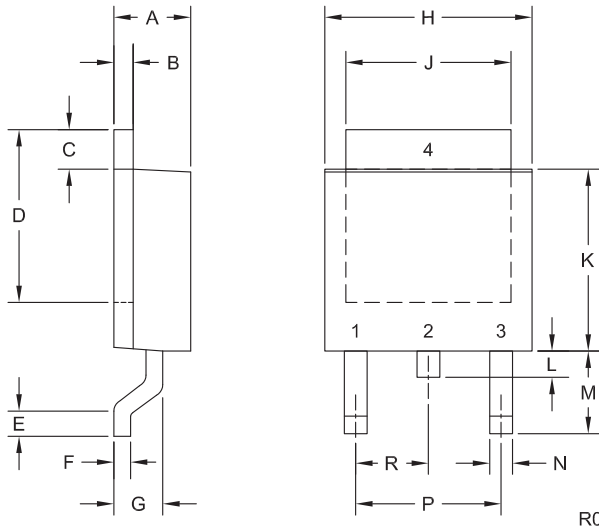


ELECTRICAL CHARACTERISTICS - Continued: ($T_C=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	TYP	UNITS
$Q_{g(\text{tot})}$	$V_{DS}=560\text{V}, V_{GS}=10\text{V}, I_D=7.0\text{A}$ (Note 2)	18.8	nC
Q_{gs}	$V_{DS}=560\text{V}, V_{GS}=10\text{V}, I_D=7.0\text{A}$ (Note 2)	2.5	nC
Q_{gd}	$V_{DS}=560\text{V}, V_{GS}=10\text{V}, I_D=7.0\text{A}$ (Note 2)	12.3	nC
$t_{d(\text{on})}$	$V_{DD}=350\text{V}, V_{GS}=10\text{V}, I_D=7.0\text{A}, R_G=10\Omega$ (Note 2)	10.7	ns
t_r	$V_{DD}=350\text{V}, V_{GS}=10\text{V}, I_D=7.0\text{A}, R_G=10\Omega$ (Note 2)	33.4	ns
$t_{d(\text{off})}$	$V_{DD}=350\text{V}, V_{GS}=10\text{V}, I_D=7.0\text{A}, R_G=10\Omega$ (Note 2)	54.0	ns
t_f	$V_{DD}=350\text{V}, V_{GS}=10\text{V}, I_D=7.0\text{A}, R_G=10\Omega$ (Note 2)	27.7	ns
t_{rr}	$V_{GS}=0, I_S=7.0\text{A}, di/dt=100\text{A}/\mu\text{s}$ (Note 2)	395	ns
Q_{rr}	$V_{GS}=0, I_S=7.0\text{A}, di/dt=100\text{A}/\mu\text{s}$ (Note 2)	2.9	μC

Note 2: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

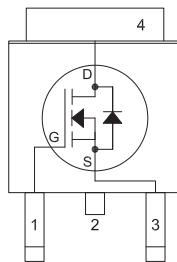
DPAK CASE - MECHANICAL OUTLINE



SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.083	0.108	2.10	2.75
B	0.016	0.032	0.40	0.81
C	0.035	0.063	0.89	1.60
D	0.203	0.228	5.15	5.79
E	0.020	-	0.51	-
F	0.018	0.024	0.45	0.60
G	0.051	0.071	1.30	1.80
H	0.248	0.268	6.30	6.81
J	0.197	0.217	5.00	5.50
K	0.209	0.245	5.30	6.22
L	0.025	0.040	0.64	1.02
M	0.090	0.115	2.30	2.91
N	0.012	0.045	0.30	1.14
P	0.180		4.60	
R	0.090		2.30	

DPAK (REV: R0)

PIN CONFIGURATION



LEAD CODE:

- 1) Gate
- 2) Drain
- 3) Source
- 4) Drain

Pin 2 is common to the tab (4)

MARKING: FULL PART NUMBER

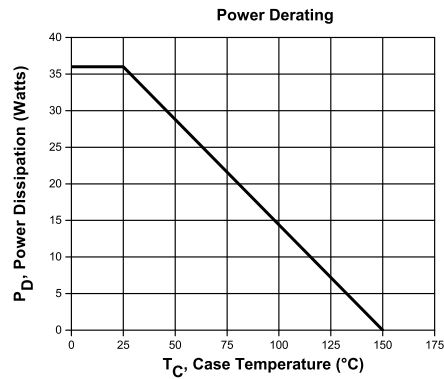
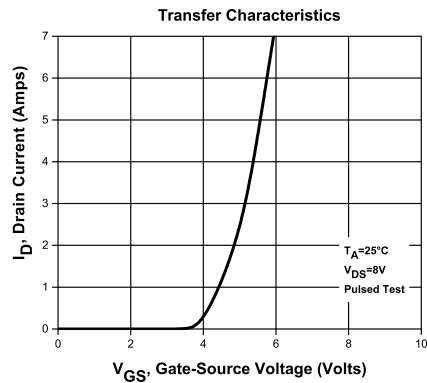
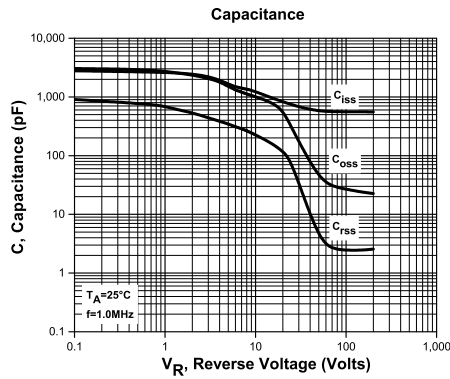
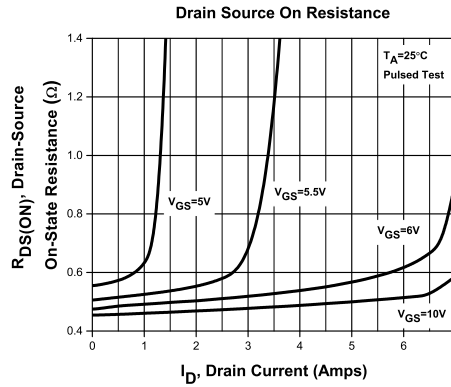
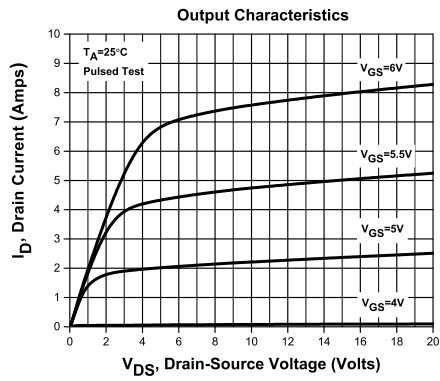
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TYPICAL ELECTRICAL CHARACTERISTICS



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OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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